

OFFICE OF THE DEPUTY VICE CHANCELLORACADEMICS, STUDENT AFFAIRS AND RESEARCH

UNIVERSITY EXAMINATIONS

2023 /2024 ACADEMIC YEAR

THIRD YEAR SECOND SEMESTER REGULAR EXAM

FOR THE DEGREE OF BACHELOR OF **EDUCATION SCIENCE**

COURSE CODE: PHY 322

COURSE TITLE: DIGITAL ELECTRONICS

DATE: 23RD, APRIL, 2024

TIME: 2PM - 5PM

INSTRUCTION TO CANDIDATES

SEE INSIDE

THIS PAPER CONSISTS OF 3 PRINTED PAGES

PLEASE TURN OVER

MAIN EXAM PHY 322: DIGITAL ELECTRONICS

STREAM: BED (Science)

DURATION:

INSTRUCTIONS TO CANDIDATES

i. Answer TWO questions in section A and any other THREE questions in section B.

SECTION A (28 MARKS)

Question One (14 Marks)	(2.36-1-)
(a) List three main ways of specifying the function of a combinational logic circuit	(3 Marks)
(b) With aid of a diagram explain the Static I-V Characteristics of a junction diode(c) Distinguish between holes and free electrons in semiconductor physics	(7 Marks) (4 marks)
 Question Two (14 Marks) (a) With aid of well labeled diagrams distinguish between analog and digital signal (b) State three advantages of presenting data using Digital Signals (c) Convert 01102 into a decimal number. (d) Convert the following hexadecimal numbers into equivalent octal numbers. i) A72E 	(4 marks) (3 Marks) (2 Marks) (4 Marks)
ii) 4.BF85	
(e) What are Logic Gates?	(1 Mark)
SECTION B (42 MARKS)	
Question Three (14 Marks)	
(a) What are universal gates?	(2 Marks)
(b) List types of universal gates	(2 Marks)
(c) Define the term shift register.	(2 Marks)
(d) State the differences between a serial shift and a parallel shift register.	(2 Marks)

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(e) Contrast between combinational logic circuits and sequential logic circuits clearly stating all the differences with respect to their output, memory and fundamental building block. (6 Marks)

Qı	uestion Fou	ur (14 Marks)		
(a) Explain how a depletion layer is formed in a P-N junction				
(b) Explain the following Technical Characteristics of memory elements				
	i.	Access time	(1 Mark)	
	ii.	Cycle time	(1 Mark)	
	iii.	Throughput	(1 Mark)	
	iv.	Non-volatility	(1 Mark)	
	(c) Based	on construction, list four types of basic registers used in digital ele	ectronics	
			(4 Marks)	
Qu	estion Fiv	e (14 Marks)		
	(a) Simpl	lify the Boolean function $F = AB + (AC)' + AB'C (AB + C)$.	(4 Marks)	
	(b) Simpli	ify the Boolean function $F = XYZ + XY'Z + XYZ'$.	(3 Marks)	
(c) What is a Half Adder, draw its logic diagram			(4 Marks)	
	(d) Give a	Truth table for the half adder	(3 Marks)	
Qu	estion Six	(14 Marks)		
		is the function of a Karnaugh map.	(2 Marks)	
		he various types of Karnaugh maps	(3 Marks)	
	(c) What i	is a counter?	(2 Marks)	
	(d) State ti	he main categories of sequential circuits.	(3 Marks)	
	(e) State to	wo common features in both latch and flip flop.	(2 Marks)	
	(f) Differe	entiate between Synchronous and asynchronous sequential logic co	ircuits. (2 Marks)	
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Qu	estion Sev	en (14 Marks)		
	(a) His	ghlight any three Bipolar Transistor Configurations	(3 Marks)	
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(b) Using well labeled diagram, explain the working mechanism of a MOSFET (11 Marks)